

Erratum: Electronic and thermoelectric properties of CoSbS and FeSbS
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Experimental Hall carrier concentrations for *n*-type CoSbS were inadvertently reported incorrectly. Actual Hall carrier concentrations are an exact factor of 10 higher than reported in the original publication. This also means that the 300 K Hall mobility reported in Sec. III is in fact $4.5 \text{ cm}^2/\text{V sec}$, not $45 \text{ cm}^2/\text{V sec}$. This removes much of the reported discrepancy between carrier concentrations inferred from the temperature dependence of the thermopower and those reported from Hall measurements. Other conclusions from the paper, such as those regarding the potential for improved performance in optimized samples, remain unchanged.